SILICON NPN DUAL TRANSISTORS



2N3904DCSM

Features:

- Hermetic Ceramic Surface Mount Package
- Designed For General Purpose and Switching Applications
- Screening Option Available



Absolute Maximum Ratings (T_A = 25°C unless otherwise noted)

| | | | Each Side | Total Device |
|------------------|-----------------------------|---------------------------------|-----------|----------------------|
| V _{CBO} | Collector – Base Voltage | | 60V | |
| V _{CEO} | Collector – Emitter Voltage | | 40V | |
| V _{EBO} | Emitter – Base Voltage | | 6V | |
| IС | Collector Current | | 200mA | |
| PD | Total Power Dissipation at | T _A = 25°C | 500mW | 600mW ⁽¹⁾ |
| | | Derate Above 25°C | 2.86mW/°C | 3.43mW/°C |
| Тј | Junction Temperature Range | | -55 to - | +200°C |
| T _{stg} | Storage Temperature Range | Temperature Range -55 to +200°C | | +200°C |

Thermal Properties (Each Side)

| R _{OJA} Thermal Resistance Junction to Ambient | Max. 350°C/W |
|---|--------------|
|---|--------------|

Notes

(1) Total device power dissipation limited by package.

General Note

TT Electronics reserves the right to make changes in product specification without notice or liability. All information is subject to TT Electronics' own data and is considered accurate at time of going to print.

Semelab Welwyn TT Electronics | Welwyn Components Limited Welwyn Electronics Park, Bedlington, Northumberland, NE22 7AA, UK Ph: +44 (0) 1670 822181 www.ttelectronics.com | Bedlington.sales@ttelectronics.com Classification: Public 9009 Iss 2 Page 1 of 4

SILICON NPN DUAL TRANSISTORS



2N3904DCSM

Electrical Specifications

Electrical Characteristics (Each Side, T_A = 25° C unless otherwise noted)

| SYMBOL | PARAMETER | TEST CONDITIONS | | MIN | ТҮР | MAX | UNITS |
|--------------------------------|--------------------------------------|----------------------------------|------------------------|--|-----|------|-------|
| V(BR)CEO ⁽²⁾ | Collector-Emitter Breakdown Voltage | I _C = 1.0mA | I _B = 0 | 40 | | | V |
| V _{(BR)CBO} | Collector-Base Breakdown Voltage | l _C = 10μA | I _E = 0 | 60 | | | V |
| V _{(BR)EBO} | Emitter-Base Breakdown Voltage | I _E = 10μΑ | I _C = 0 | 6 | | | V |
| ICEX | Collector-Emitter Cut-off Current | V _{CE} = 30V | V _{EB} = 3V | | | 50 | nA |
| V (2) | | I _C = 10mA | I _B = 1.0mA | | | 0.2 | V |
| VCE(sat) | Collector-Emitter Saturation Voltage | ector-Emitter Saturation Voltage | | | 0.3 | V | |
| | | I _C = 10mA | I _B = 1.0mA | 0.65 | | 0.85 | V |
| VBE(sat) | Collector-Base Saturation Voltage | I _C = 50mA | I _B = 5mA | 40 60 6 0.65 0.65 40 70 100 60 30 | | 0.95 | V |
| | DC Current Gain | V _{CE} = 1.0V | I _C = 0.1mA | 40 | | | |
| h _{FE} ⁽²⁾ | | V _{CE} = 1.0V | I _C = 1.0mA | 70 | | | |
| | | V _{CE} = 1.0V | I _C = 10mA | 100 | | 300 | |
| | | V _{CE} = 1.0V | I _C = 50mA | 60 | | | |
| | | V _{CE} = 1.0V | I _C = 100mA | 30 | | | |

Notes

(2) Pulse Width \leq 380us, $\delta \leq$ 2%

General Note

TT Electronics reserves the right to make changes in product specification without notice or liability. All information is subject to TT Electronics' own data and is considered accurate at time of going to print.

Semelab Welwyn TT Electronics | Welwyn Components Limited Welwyn Electronics Park, Bedlington, Northumberland, NE22 7AA, UK Ph: +44 (0) 1670 822181 www.ttelectronics.com | Bedlington.sales@ttelectronics.com Classification: Public 9009 lss 2 Page 2 of 4

SILICON NPN DUAL TRANSISTORS



2N3904DCSM

Dynamic Characteristics (Each Side, T_A = 25° C unless otherwise noted)

| SYMBOL | PARAMETER | TEST CONDITIONS | MIN | ТҮР | ΜΑΧ | UNITS |
|--------------------------------|---------------------------|--|-----|-----|-----|--------------------|
| f _T | Transition Frequency | V _{CE} = 20V I _C = 10mA f = 100MHz | 250 | 300 | | MHz |
| C _{obo} | Output Capacitance | V _{CB} = 5V I _E = 0 f = 1.0MHz | | | 4 | pF |
| C _{ibo} | Input Capacitance | V _{BE} = 0.5V I _C = 0 f = 1.0MHz | | | 8 | pF |
| h _{ie} ⁽³⁾ | Input Impedance | | 1.0 | | 10 | ΚΩ |
| h _{oe} ⁽³⁾ | Output Admittance | V _{CE} = 20V I _C = 1.0mA | 1.0 | | 40 | μS |
| h _{re} ⁽³⁾ | Voltage Feedback Ratio | f = 1.0KHz | 0.5 | | 8 | x 10 ⁻⁴ |
| h _{fe} | Small Signal Current Gain | | 100 | | 400 | |
| N _F ⁽³⁾ | Noise Figure | V _{CE} = 5V I _C = 100μA f = 1.0KHz R _S = 1.0KΩ | | | 5 | dB |
| t _d | Delay Time | V _{CC} = 3V I _C = 10mA | | | 35 | ns |
| t _r | Rise Time | I _{B1} = 1.0mA | | | 35 | ns |
| t _s | Storage Time | V _{CC} = 3V I _C = 10mA | | | 200 | ns |
| t _f | Fall Time | I _{B1} = -I _{B2} = 1 .0mA | | | 50 | ns |

Notes

(3) By design only, not a production test

General Note

TT Electronics reserves the right to make changes in product specification without notice or liability. All information is subject to TT Electronics' own data and is considered accurate at time of going to print.

Semelab Welwyn TT Electronics | Welwyn Components Limited Welwyn Electronics Park, Bedlington, Northumberland, NE22 7AA, UK Ph: +44 (0) 1670 822181 www.ttelectronics.com | Bedlington.sales@ttelectronics.com Classification: Public 9009 Iss 2 Page 3 of 4

SILICON NPN DUAL TRANSISTORS

2N3904DCSM



Mechanical Data

Dimensions in mm (Inches)



LCC2 (MO-041BB)

Underside View

| Pad 1 – Collector 1 | Pad 4 – Collector 2 |
|---------------------|---------------------|
| Pad 2 – Base 1 | Pad 5 – Emitter 2 |
| Pad 3 – Base 2 | Pad 6 – Emitter 1 |

PART NUMBER VARIANTS

| Part Number Reference | Termination Finish ⁽ⁱ⁾ | SML ROHS |
|-----------------------|-----------------------------------|--------------------|
| 2N3904DCSM | Gold (Au) | G4 ⁽ⁱⁱ⁾ |

Notes:

i. Other lead finish options available. Specify lead finish requirements at point of order.

ii. G4 = e4 as defined in J-STD-609 2nd Level Interconnect Category.

General Note

TT Electronics reserves the right to make changes in product specification without notice or liability. All information is subject to TT Electronics' own data and is considered accurate at time of going to print.

© TT Electronics plc

Semelab Welwyn TT Electronics | Welwyn Components Limited Welwyn Electronics Park, Bedlington, Northumberland, NE22 7AA, UK Ph: +44 (0) 1670 822181 www.ttelectronics.com | Bedlington.sales@ttelectronics.com Classification: Public 9009 Iss 2 Page 4 of 4